SURFACE MOUNT SILICON CURRENT LIMITING DIODES





www.centralsemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CDCLD200, CDCLD400, and CDCLD500 are Current Limiting Diodes (CLDs) specifically designed for applications requiring a constant current over a wide voltage range. The series is designed with a unique process that holds regulator current constant over temperature excursions (zero temperature coefficient). The devices are available in the thermally efficient DPAK package outline.

MARKING: FULL PART NUMBER

FEATURES:

- · Zero temperature coefficient
- · High regulator currents available
- · Industry standard thermally efficient DPAK

MAXIMUM RATINGS: (T _A =25°C unless otherwise noted)								
	SYMBOL	CDCLD200	CDCLD400	CDCLD500	UNITS			
Peak Operating Voltage	Pov	27	13.5	10.8	V			
Peak Operating Voltage (T _C =35°C)	Pov		50		V			
Power Dissipation (Note 1)	P_{D}		6.25		W			
Power Dissipation (T _C =35°C) (Note 1)	P_{D}		28.75		W			
Thermal Resistance	Θ JC		4.0		°C/W			
Operating and Storage Junction Temperature	T _J , T _{stg}		-55 to +150		°C			

Note 1: Mounted on 900mm² 4-layer PCB with 2-ounce copper traces.

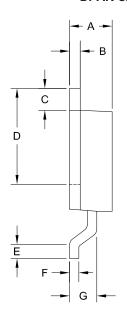
ELECTRICAL CHARACTERISTICS: (TA=25°C)

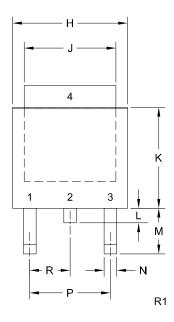
Туре		Maximum Limiting Voltage (tp=5.0ms) VL @ 0.8 x Ip MIN		
	MIN mA	NOM mA	MAX mA	V
CDCLD200	170	200	230	2.0
CDCLD400	340	400	460	2.0
CDCLD500	425	500	575	2.0

SURFACE MOUNT SILICON **CURRENT LIMITING DIODES**



DPAK CASE - MECHANICAL OUTLINE



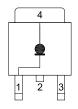


LEAD CODE:1) Cathode

- 2) Anode
- 3) No Connection
- 4) Anode

Pin 2 is common to the tab (4)

MARKING: FULL PART NUMBER



DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
Α	0.083	0.108	2.10	2.75			
В	0.016	0.032	0.40	0.81			
С	0.035	0.063	0.89	1.60			
D	0.203	0.228	5.15	5.79			
E	0.020	-	0.51	-			
F	0.016	0.024	0.40	0.60			
G	0.051	0.071	1.30	1.80			
Н	0.248	0.268	6.30	6.81			
J	0.197	0.217	5.00	5.50			
K	0.209	0.245	5.30	6.22			
L	0.025	0.040	0.64	1.02			
М	0.090	0.115	2.30	2.91			
N	0.012	0.045	0.30	1.14			
Р	0.180		4.60				
R	0.090		2.30				
DDAK (DE\/· D1)							

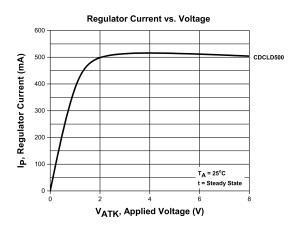
DPAK (REV: R1)

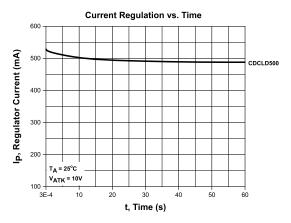
R4 (1-April 2021)

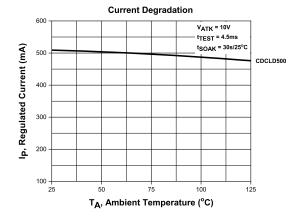
SURFACE MOUNT SILICON CURRENT LIMITING DIODES

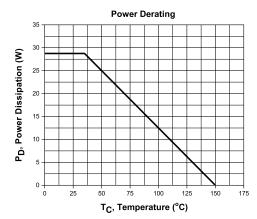


TYPICAL ELECTRICAL CHARACTERISTICS













TYPICAL APPLICATIONS

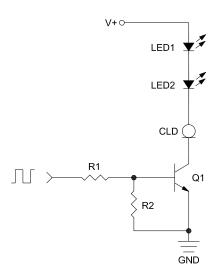


Figure 1. CLDs can be used to limit the current flowing through LED strings. Their dynamic performance make them an excellent replacement for current limiting resistors, as they allow for continuous current regulation regardless of input voltage. LED strings like this are commonly used in dimming lighting systems. By using a PWM input to control the transistor, the LED luminosity can be controlled by extending or decreasing the pulse width, allowing for control over the brightness of the LED.





TYPICAL APPLICATIONS

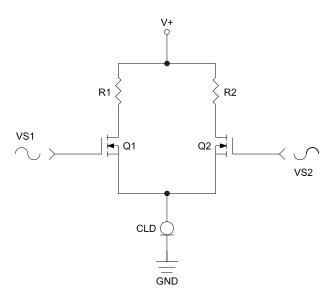


Figure 2. When designing differential amplifiers, it is essential to use a high impedance tail resistor to control both differential and common mode function. For differential signals, the tail resistor effectively splits the current amongst the transistors. This ensures proportional current increase and decrease between the transistors. The high impedance drives down the common mode gain and increases the common mode rejection ratio, thus yielding a more ideal amplifier. Ideally, an infinite impedance current source would be used in place of the tail resistor. While the ideal current source doesn't exist, CLDs serve as an excellent replacement for the tail resistor and also perform much like an active current source, both regulating the circuit to a constant current and presenting a large tail impedance. This yields a larger CMRR than using a high impedance tail resistor would.